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## List of Acronyms

Alq<sub>3</sub> tris(8-hydroxyquinoline) aluminum(III)

BCP 9-dimethyl-4,7-diphenyl-1, 10-phenanthroline

CBP 4, 4'-bis(9-carbazolyl)-1,1'-biphenyl

**CDBP** 4,4'-bis(9-carbazolyl)-2,2'-dimethyl-biphenyl

CF color filter

CIE Commission Internationale d'Eclairage

**CRTs** cathode ray tubes

CuPc copper phthalocyanine

CV cyclicvoltametric

**DI** deionized

DMCT dopant-to-matrix charge transfer

EL electroluminescent

EML emitting material Layer

ETL electron transport layer

EQE external quantum efficiency

FIr6 bis[4',6'-difluoro- phenylpyridinato)tetrakis(1-pyrazolyl)borate]

FWHM full width at half maximum

HBL hole and exciton blocking layer

HOMO highest occupied molecular orbital

HTL hole transport layer

IQE internal quantum efficiency

Ir-complex iridium (III) complex

ISC intersystem crossing



ITO indium-tin-oxide

I-V current-voltage

LCDs liquid crystal displays

LED light emitting device

LUMO lowest unoccupied molecular orbital

mCP 1,3-Bis(carbazol-9-yl)benzene

MLCT metal to ligand charge transfer

NMP N-Methyl-2-Pyrrolidone

**NPB** 4,4'-bis[(1-naphthyl)(phenyl)amino]-1, 1-biphenyl

**α-NPD** 4,4'-bis[N-(1-naphthyl)-N-phenyl-amino]biphenyl

OLED organic light emitting devices

PDAs potential applications

**PEDOT** polyethylene dioxythiophene

PL Photoluminescence

PLQY photoluminescence quantum yield

PVK polyvinylcarbazole

QE quantum efficiency

QY quantum yield

RGB red, green and blue

SOC spin-orbit coupling

TBP Tri-n-butylphosphine

TCTA 4,4',4"-tris(N-carbazolyl)triphenylamine

TPD N, N'-diphenyl-N, N'-di(3-methylphenyl)-1,1'-biphenyl-4,4'-diamine

UV ultra-violet

UV-VIS ultraviolet-visible

WOLEDs white organic light-emitting devices